

Multilayer Power Inductor

CIG32W Series (3225/ EIA 1210)

APPLICATION

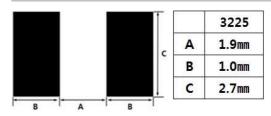
Mobile phones, DSC, DVC, PDA etc. for DC-DC Converter

FEATURES

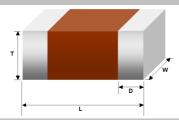
- High Current Type
- · Low DC resistance
- Magnetically shielded structure
- Free of all RoHS-regulated substances
- · Monolithic structure for high reliability



RECOMMENDED LAND PATTERN



DIMENSION



TYPE	Dimension [mm]				
1117	L	W	Т	D	
32	3.2±0.2	2.5±0.2	0.9±0.1	0.5±0.3	

DESCRIPTION

Part no.	Size	Inductance	DC	Rated Current (A)*1 Typ.	Rated Current (A)*2	
	(inch/mm)	(uH)@1MHz	Resistance(Ω)		Max.	Тур.
CIG32W1R0MNE	1210/3225	1.0±20%	0.06±25 %	2.7	1.5	2.0

**Rated Current (A) *1: DC current value when Inductance drops to 30% of nominal Inductance value (ONLY REFERENCE)

1000

10

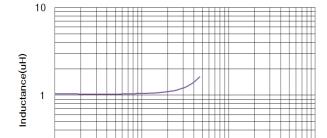
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100

*Test equipment: Agilent :E4991A+16092A

CHARACTERISTIC DATA

0

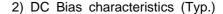


Frequency(MHz)

1) Frequency characteristics (Typ.)

1 10 100 1000 10000

Current(mA)







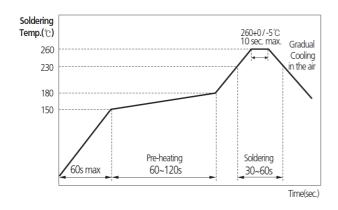
CI	G	32	W	1R0	M	N	Ε
(1)	(2)	(3)	(4)	(5)	(6)	(7)	(8)

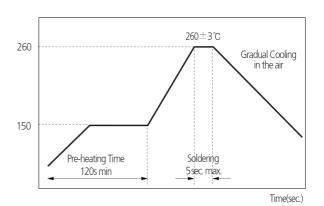
- (1) Chip Inductor
- (3) Dimension
- (5) Inductance (1R0:1.0uH)

- (2) Power Inductor
- (4) Product Series (W:Normal Type)
- (6) Tolerance (M:±20%)
- (7) Thickness option(N:Standard, A:Thinner than standard, B:Thicker than standard)
- (8) Packaging(C:paper tape, E:embossed tape)

REFLOW SOLDERING

FLOW SOLDERING





Packaging Style	Quantity(pcs/reel)
Embossed Taping	2,500

Any data in this sheet are subject to change, modify or discontinue without notice. The data sheets include the typical data for design reference only. If there is any question regarding the data sheets, please contact our sales personnel or application engineers.